

Switchmode Full Plastic Dual Ultrafast Power Rectifiers

Designed for use in switching power supplies, inverters and as free-wheeling diodes. These state-of-the-art devices have the following

Features

- * High Surge Capacity
- * Low Power Loss, High efficiency
- *150°C Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction
- *Low Forward Voltage , High Current Capability
- * High-Switching Speed Recovery Time
- * Plastic Material used Carries Underwriters Laboratory
- * Flammability Classification 94V-O

* Pb free

* In compliance with EU RoHs directives



MAXIMUM RATINGS

Characteristic	Symbol	URF2020C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	200	V
RMS Reverse Voltage	V _{R(RMS)}	140	V
Average Rectifier Forward Current (per diode) Total Device (Rated V _R)	I _{F(AV)}	10 20	А
Peak Repetitive Forward Current Rate V _R , Square Wave, 20kHz,	I _{FM}	20	А
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase, 60Hz)	I _{FSM}	200	A
Operating Junction Temperature	T _{Jg}	150	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Maximum Instantaneous Forward Voltage ($I_F = 10 \text{ Amp } T_C = 25^{\circ}C$) ($I_F = 10 \text{ Amp } T_C = 125^{\circ}C$)	V _F		0.920 0.760	0.975 	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)	I _R		0.02 10.0	10.0 	uA
Reverse Recovery Time (I _F = 0.5 A, I _R =1.0,I _{rr} =0.25 A)	T _{rr}			35	ns
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	CP		140		₽F

URF2020C

Ultrafast Power RECTIFIERS

> 20 AMPERES 200 VOLTS











URF2020C

FIG-3 FORWARD CURRENT DERATING CURVE

20

16

12

8

0 L

350

-1.0A

25

50

75

LEAD TEMPERATURE (°C)

FIG-4TYPICAL JUNCTION CAPACITANCE

100

125

f = 1 M H z T a = 2 5 °C

150

AVERAGE FORWARD RECTIFIED CURRENT (Amp.)





FORWARD VOLTAGE (Volts)



Notes:

1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50 Ω

Set time base for 10/20 ns/cm FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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